TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

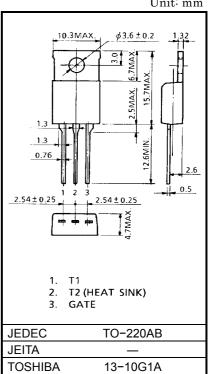
# SM6G45, SM6J45, SM6G45A, SM6J45A

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V<sub>DRM</sub> = 400, 600V
- **R.M.S ON-State Current** .
- : IT (RMS) = 6A
- High Commutating (dv / dt)

#### **MAXIMUM RATINGS**

CHARACTERI	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off− State Voltage	SM6G45 SM6G45A	V <sub>DRM</sub>	400	V	
	SM6J45 SM6J45A	VDRM	600		
R.M.S On-State Curren (Full Sine Waveform Tc	•	I <sub>T (RMS)</sub>	6	А	
Peak One Cycle Surge On-State		l	60 (50Hz)	А	
Current (Non-Repetitive	2)	ITSM	66 (60Hz)	~	
I <sup>2</sup> t Limit Value		l <sup>2</sup> t	18	A <sup>2</sup> s	
Critical Rate of Rise of C Current	0n−State	di / dt	50	Α/μs	
Peak Gate Power Dissip	ation	P <sub>GM</sub>	5	W	
Average Gate Power Dis	ssipation	P <sub>G (AV)</sub>	0.5	W	
Peak Gate Voltage		V <sub>GM</sub>	10	V	
Peak Gate Current		I <sub>GM</sub>	2	А	
Junction Temperature		Тј	-40~125	°C	
Storage Temperature Ra	ange	T <sub>stg</sub>	-40~125	°C	



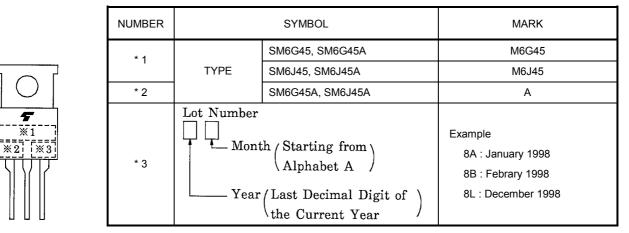
Weight: 2.0g

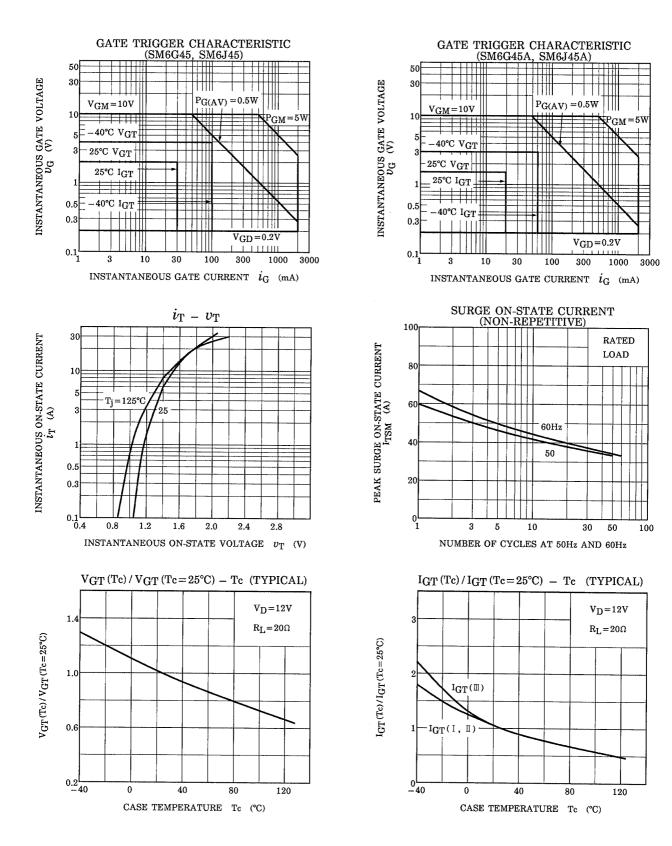
Unit: mm

### ELECTRICAL CHARACTERISTICS (Ta = 25°C)

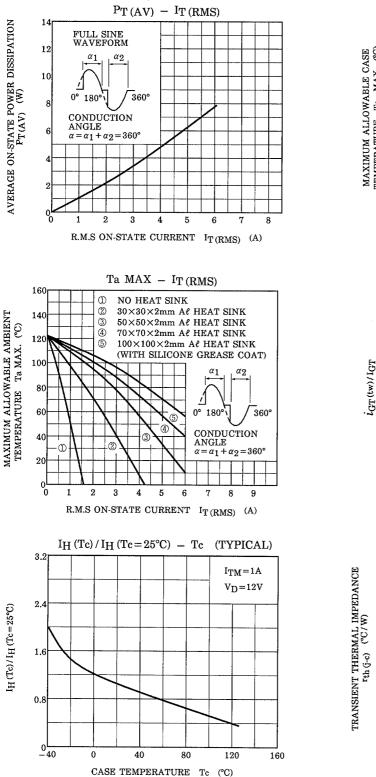
CHARACTERISTIC			SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I <sub>DRM</sub>	V <sub>DRM</sub> = Rated, T <sub>j</sub> = 125°C		_	_	2	mA		
Gate Trigger Voltage			I	V <sub>GT</sub>	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)		_	2	- V
	SM6G45 SM6J45	5	Ш			T2 (+), Gate (−)	_	_	2	
		5	Ш			T2 (-), Gate (-)	_	_	2	
			IV			T2 (-), Gate (+)	_	_	_	
			I			T2 (+), Gate (+)		_	1.5	
	SM6G45/ SM6J45A	5A	Ш			T2 (+), Gate (-)		_	1.5	
		δA	III			T2 (-), Gate (-)		_	1.5	
			IV			T2 (-), Gate (+)		_	—	
Gate Trigger Current	SM6G45 SM6J45		I	I <sub>GT</sub>	V <sub>D</sub> = 12V R <sub>L</sub> = 20Ω	T2 (+), Gate (+)		_	30	- mA
		5	Ш			T2 (+), Gate (-)		_	30	
		5	III			T2 (-), Gate (-)		_	30	
			IV			T2 (-), Gate (+)		_	_	
	SM6G45		I			T2 (+), Gate (+)		_	20	
		5A	Ш			T2 (+), Gate (-)		_	20	
	SM6J45	δA	III			T2 (-), Gate (-)		_	20	
			IV	1		T2 (-), Gate (+)		_	_	
Peak On-State Voltage			V <sub>TM</sub>	I <sub>TM</sub> = 9A		-	_	1.5	V	
Gate Non-Trigger Voltage		V <sub>GD</sub>	V <sub>D</sub> = Rated, Tc = 125°C		0.2	_	_	V		
Holding Current			Ι <sub>Η</sub>	V <sub>D</sub> = 12V, I <sub>TM</sub> = 1A		_	_	50	mA	
Thermal Resistance		R <sub>th (j−c)</sub>	Junction to Case, AC		_	_	2.5	°C/W		
Critical Rate of SM6G Rise of Off-SM6J			(a), (a)) -	V <sub>DRM</sub> = 400V, (di / dt) c = -3.3A / ms		10	_	_	V / µs	
State Voltage at Commutation		SM6G45A SM6J45A		(dv / dt) c	(a1 / a1) c = -3.3A / ms T <sub>j</sub> = 125°C		4	—	_	v / µs

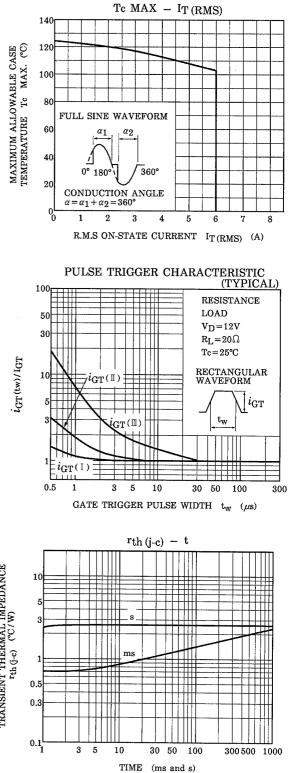
#### MARKING





## TOSHIBA





#### **RESTRICTIONS ON PRODUCT USE**

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.